SIEMENS

1550 nm Laser in Coaxial Package with SM-Pigtail, Medium Power

• Designed for application in fiber-optic networks

- Laser diode with Multi-Quantum Well structure
- Suitable for bit rates up to 1 Gbit/s
- Ternary photodiode at rear mirror for monitoring and control of radiant power
- Hermetically sealed subcomponent, similar to TO 18
- SM Pigtail with optional flange



Туре	Ordering Code	Connector/Flange
STM 81004G	Q62702-Pxxxx	FC / without flange
STM 81004A	Q62702-Pxxxx	DIN / without flange
STM 81005G	Q62702-Pxxxx	FC / with flange
STM 81005A	Q62702-Pxxxx	DIN / with flange

Component with other connector types on request.

Maximum Ratings

Output power ratings refer to the SM fiber output. The operating temperature of the submount is identical to the case temperature.

Parameter	Symbol	Values	Unit
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Module

Operating temperature range at case	T _C	– 40 + 85	°C
Storage temperature range	T _{stg}	– 40 + 85	°C
Soldering temperature $t_{max} = 10 \text{ s}, 2 \text{ mm}$ distance from bottom edge of case	T _S	260	°C

STM 81004X STM 81005X

Maximum Ratings (cont'd)

Parameter	Symbol	Values	Unit
Laser Diode			
Direct forward current	I _{F max}	120	mA
Radiant power CW	Φ_{e}	2	mW
Reverse voltage	V _{R max}	2	V
Monitor Diode			
Reverse voltage	V _{R max}	10	V

Characteristics

All optical data refer to a coupled 10/125 μ m SM fiber, T_{C} = 25 °C.

Parameter S	Symbol	Values	Unit
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Laser Diode

Optical output power	Φ_{e}	> 1.2	mW
Emission wavelength center of range $\Phi_e = 0.5 \text{ mW}$	λ	1510 1590	nm
Spectral bandwidth Φ_{e} = 0.5 mW (RMS)	Δλ	< 5	nm
Threshold current (- 40 + 85 °C)	I _{th}	8 60	mA
Forward voltage Φ_{e} = 0.5 mW	V_{F}	< 1.5	V
Radiant power at threshold	Φ_{eth}	< 40	μW
Slope efficiency	η	20 100	mW/A
Differential series resistance	r _S	< 8	Ω
Rise time/fall time	t _R , t _F	< 1	ns
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Monitor Diode

Dark Current, V_{R} = 5 V, Φ_{e} = 0	I _R	< 500	nA
Photocurrent, Φ_{e} = 0.5 mW	I _P	100 1000	μA

Laser Diode

Radiant Power in Singlemode Fiber



Relative Radiant Power

 $\Phi_{e} = f(\lambda)$



Laser Forward Current $I_{\mathsf{F}} = f(V_{\mathsf{F}})$



Monitor Diode Dark Current $I_R = f(T_A)$ $\Phi_{port} = 0, V_R = 5 V$



Package Outlines (Dimensions in mm)



STM 81004X



STM 81005X

Semiconductor Group